

The NMOS transistor has $K_P = 50 \mu\text{A}/\text{V}^2$, $L = 10 \mu\text{m}$, $W = 160 \mu\text{m}$, $r_d = \infty$, and $V_{DD} = 1 \text{ V}$. Find the value for R_S to achieve a drain current of $I_D = 50 \mu\text{A}$. Then, compute the voltage across the drain and output resistance.

UCLA
Electrical and Computer Department
ECE 100
Second Midterm

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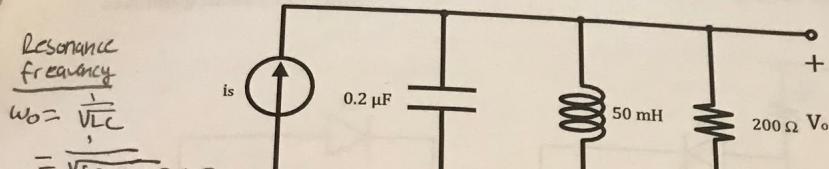
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Problems	Points
1	17 /20
2	9 /14
3	17 /20
4	0 /6
5	12 /20
6	20 /20
Total	75 /100

The NMOS transistor has $KP = 50 \mu A/V^2$, $L = 10 \mu m$, $W = 160 \mu m$, $r_d = \infty$, $V_{DD} = 1 V$. Find the value for R_S to achieve $I_{DS} = 1 A$. Then, compute the voltage gain, output resistance, and output resistance.

1. For the circuit shown below, find and plot magnitude and phase of $\frac{v_o}{i_s}$. Specify the resonance frequency, -3 dB frequencies and also the BW.



$$\text{Resonance frequency } \omega_0 = \frac{1}{\sqrt{LC}} = \frac{1}{\sqrt{50 \times 10^{-3} \times 0.2 \times 10^{-6}}} = 1591.5 \text{ rad/s}$$

$$f_0 = \frac{1}{2\pi\sqrt{L \cdot C}} = 1591.5 \text{ Hz}$$

$$Z_{eq} = \frac{1}{R + j(\omega C + \frac{1}{\omega L})} \quad V_o = I_S \cdot Z_{eq}$$

$$|V_o| = \frac{1}{\sqrt{R^2 + (\omega C + \frac{1}{\omega L})^2}} \rightarrow -1$$

$$\angle \frac{V_o}{I_S} = \angle R - \angle C - \angle L$$

$$= \angle R - \angle C - \angle L$$

$$= -\arctan(\frac{1}{\omega L})$$

$$= -\arctan(\frac{\omega C - \frac{1}{\omega L}}{R}) \rightarrow$$

-3dB frequency = halfway cutoff

$$|Hw| = \frac{1}{\sqrt{2}} \cdot \text{max}$$

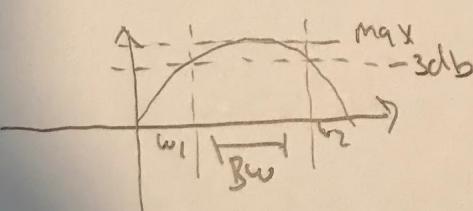
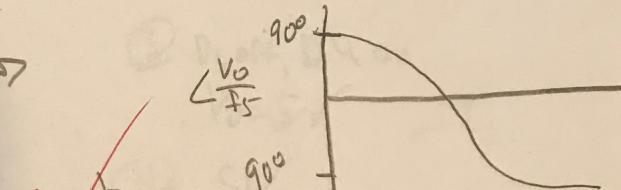
$$\omega_1 = \pm \frac{1}{2RL} + \sqrt{(\frac{1}{2RL})^2 + \omega_0^2}$$

-2

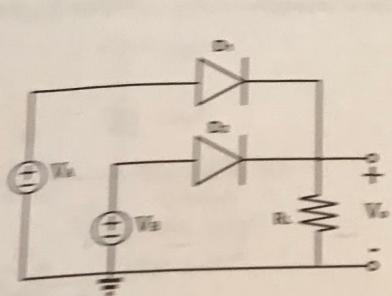
$$Q = 2\pi f_0 CR$$

$$BW = \frac{f_0}{Q}$$

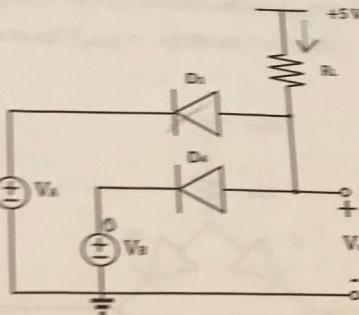
$$BW = \frac{1}{2\pi CR} = \frac{1}{2\pi(0.2 \times 10^{-6})(200)}$$



2. The circuits shown below is a kind of logic circuit. V_A and V_B independently can be 0 or +5V. There are 4 possible combinations: 1) $V_A = 0V, V_B = 0V$; 2) $V_A = 0V, V_B = +5V$; 3) $V_A = +5V, V_B = 0V$; 4) $V_A = +5V, V_B = +5V$. Show the output voltages for each case, assuming diodes are ideal.



a)



b)

$$\textcircled{1} \quad V_O$$

$$V_B = 0$$

$$\textcircled{2} \quad D_4 \text{ off}, D_3 \text{ on}$$

$$V_O = 5V$$

$$\textcircled{3} \quad D_3 \text{ off}, D_4 \text{ on}$$

$$V_O = 5V$$

$$\textcircled{4} \quad 5V$$

$V_A = 0, V_B = 0$

$V_A = 0, V_B = 5V$

5V

5V, D1 on

5V

5V

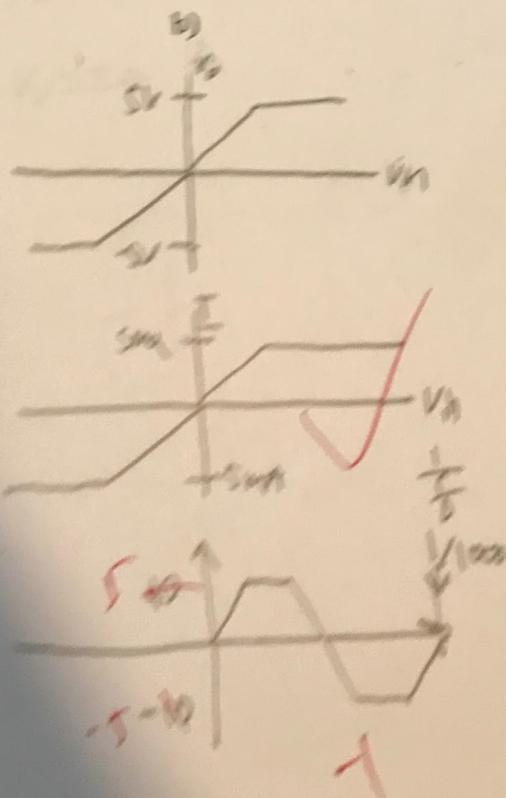
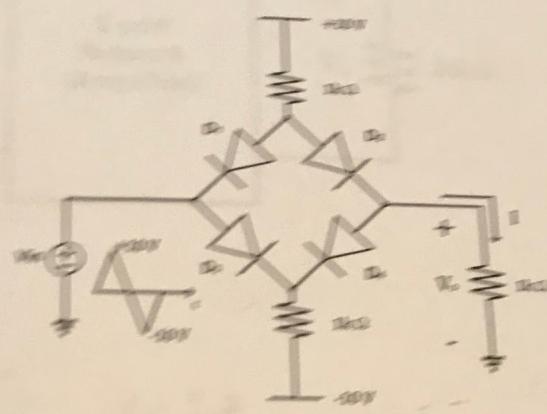
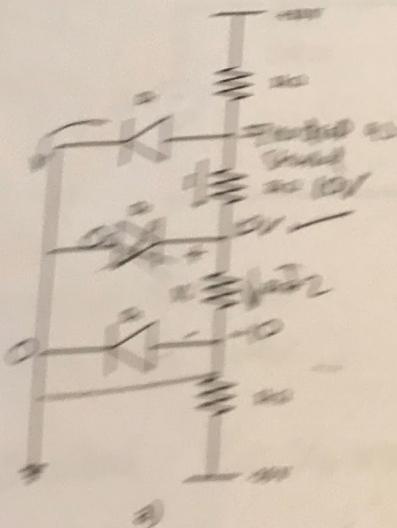
Q. Define short circuit current.

Ans: Short circuit

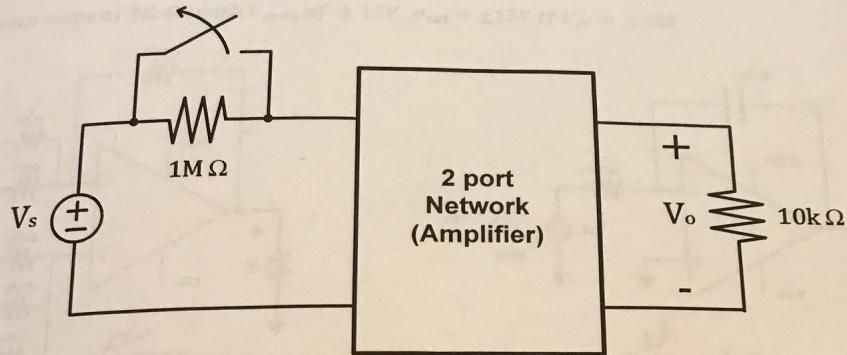
(i) Show the output voltage vs input voltage (V_o vs V_{in}) on the same xy plane.

(ii) Plot the output current vs input voltage (I_o vs V_{in}) on the same xy plane.

(iii) Plot V_o with V_{in} as a triangular waveform of $V_{peak} = +10V$ at $f = 1kHz$.



4. The output voltage of the two port network with the switch closed is 100mV. If we open the switch, the output drops to 50mV. (A way they measure the input resistance of an amplifier). Find the input impedance of the network.



$$\text{Switch closed: } V_o = 100 \text{ mV}$$

$$\text{Switch open: } V_o = 50 \text{ mV}$$

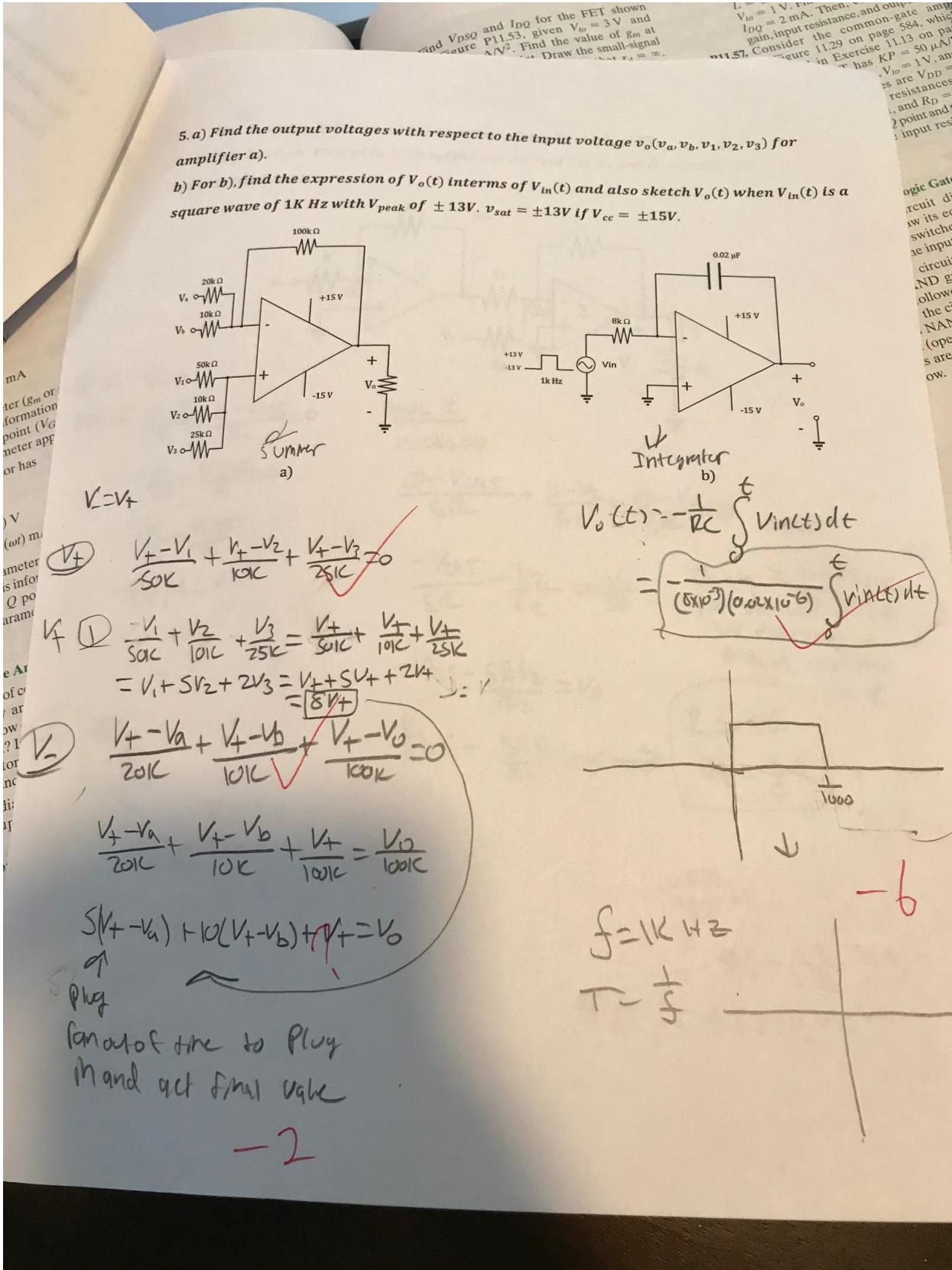
$$\text{Switch closed: } V_o = V_s / 10k$$

$$V_o = IZ$$

$$\text{Switch open: } I =$$

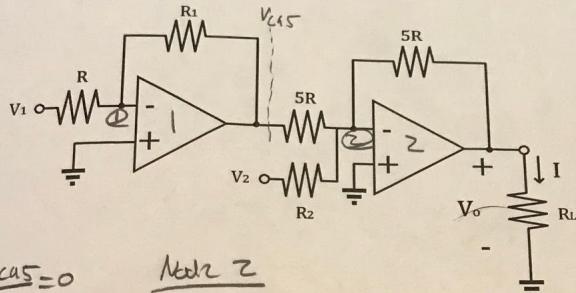
$$V_o = IZ$$

- b



The NMOS transistor has $L = 10 \mu\text{m}$, $W = 160 \mu\text{m}$, $r_d = V_{io} = 1 \text{ V}$. Find the value for R_3 to achieve $I_{DQ} = 2 \text{ mA}$. Then, compute the value of r_{min} , input resistance, and output resistance. Refer to the common-gate amplifier exercise 11.13 on page 584, which has $K_P = 50 \mu\text{A/V}^2$, $V_{DD} = 1 \text{ V}$, and $r_s = 1 \text{ k}\Omega$. The values are $V_{DD} = 1 \text{ V}$, and $R_p = 3 \text{ k}\Omega$. The point and the value of the input resistance are

6. a) Find R_1 and R_2 in terms of R if we want to have $V_o = 3V_2 - 5V_1$.
 b) If $V_1 = 2 \text{ V}$, $V_2 = 1 \text{ V}$ and $R_L = 1 \text{ k}\Omega$, find the current I if R_1 and R_2 equal to the values found in a).



$$\textcircled{1} \quad V = V_f = 0$$

$$\text{Node 1: } \frac{0 - V_1}{R} + \frac{0 - V_{c45}}{R_1} = 0$$

$$-\frac{V_1}{R} - \frac{V_{c45}}{R_1} = 0$$

$$-\frac{V_1}{R} = \frac{V_{c45}}{R_1}$$

$$-(\frac{R_1}{R})V_1 = V_{c45}$$

$$\text{Node 2}$$

$$V = V_f = 0$$

$$\frac{0 - V_{c45}}{5R} + \frac{0 - V_2}{R_2} + \frac{0 - V_o}{SR} = 0$$

$$-\frac{V_{c45}}{5R} - \frac{V_2}{R_2} = \frac{V_o}{SR}$$

$$-V_{c45} - \frac{SRV_2}{R_2} = V_o$$

$$\frac{R_1}{R}V_1 - \frac{SRV_2}{R_2} = V_o \rightarrow$$

Think $\textcircled{1}$ may have got directions mixed up resulting in negative resistance

$$\boxed{\begin{aligned} R_1 &= -5R \\ R_2 &= -\frac{5}{3}R \end{aligned}}$$

$$-\frac{5R}{R}V_2$$

$$-5V_1 - (-\frac{5}{3} \cdot SRV_2) -$$

$$-5V_1 + 3V_2 = V_o$$

$$I = \frac{(3(1) - 5(2))}{1000}$$

$$= \frac{3 - 10}{1000} = \frac{-7}{1000} = \boxed{-7 \text{ mA}}$$

Logic Gates
 Circuit diagram
 Draw its equivalent
 (switches) if the
 input is low
 AND gate. If
 followed by
 the circuit
 S NAND gate
 it (open and
 its are high.
 low.